

Comments on "Vortex phase diagram of $\text{HgBa}_2\text{Ca}_2\text{Cu}_3\text{O}_{8+\delta}$ thin films from magnetoresistance measurements"

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We make comments on the paper presented by Kim *et al.* [Phys. Rev. B **61**, 11317 (2000)]. The authors analyzed activation energies of $\text{HgBa}_2\text{Ca}_2\text{Cu}_3\text{O}_{8+\delta}$ thin films with a scaling relation, and defined four vortex regions for thin films. We find that the definitions of four vortex regions and the scaling relation are questionable when studying their definition of the resistivity range for thermally activated flux flow. Using the empirical activation energy form suggested by Zhang *et al.* [Phys. Rev. B **71**, 052502 (2005)] for lower resistivity data, we find that the form is not only in good agreement with the resistivity $\rho(T, H)$, but also with the apparent activation energy $-\partial \ln \rho(T, H) / \partial T^{-1}$.

PACS numbers: 74.25.Fy, 74.25.Ha, 74.25.Qt

Previously, Kim *et al.* [1] reported an investigation of resistive behaviors of $\text{HgBa}_2\text{Ca}_2\text{Cu}_3\text{O}_{8+\delta}$ (Hg-1223) thin films in the mixed state. A scaling relation was proposed for analyzing the resistive behavior and was found in good agreement with the apparent activation energy $-\partial \ln \rho(T, H) / \partial T^{-1}$ (the so-called effective activation energy in this paper) in a specialized resistivity range. With this scaling, they suggested that the vortex system could be divided into four different vortex regions corresponding to the flux flow (FF) region, the thermally activated flux flow (TAFF) region, the critical state region, and the vortex solid (VS) region. Three characteristic temperatures corresponding to T_{ff} , T^* , and T_{irr} were defined for the boundaries of these regions. They claimed that the TAFF behavior was limited in the region of $T^* < T < T_{ff}$ and the corresponding activation energy was expressed as $U_0(T, H) \sim H^{-1.1}(1 - T/T_c)^{1.5}$ for the magnetic field range from 1 to 9 T. In this comment, we point out that the scaling relation and the definitions of the four different vortex regions are questionable. We propose that the activation energies of Hg-1223 thin films relate to lower resistivity where $T < T^*$. Using lower resistivity data, we find that the activation energy is expressed as the form suggested by Zhang *et al.* [2].

After the discovery of high temperature superconductors (HTSCs), activation energies of different HTSCs have been widely studied in theories and experiments. According to Palstra *et al.* [3], activation energies of HTSCs should be determined in the temperature interval over which the resistivity changes from 10^{-4} to $1 \mu\Omega$ cm or for the resistivity ratio $\rho(T, H) / \rho_n$ approximately below 1%, where ρ_n is normal-state resistivity. The temperature interval is widely accepted for studying activation energies of HTSCs; besides, it is widely accepted that TAFF resistivity shall be ohmic (linear I - V relation), and the activation energy is independent of the applied current density j for $j \rightarrow 0$ [3, 4, 5, 6, 7, 8]. This means that non-ohmic behavior ought to be observed for decreasing temperature out of the TAFF region.

Using the data of Fig. 1 and Fig. 4 in Ref. [1], we

roughly redraw the $\rho(T^*, H)$ data in Arrhenius plot with gray circles as shown in Figure. 1(a), for which the data in the range of $\mu_0 H(T^*) \leq 7.0$ T were presented due to $H(T^*)$ data being only presented for $\mu_0 H(T^*) \leq 7.0$ T in Fig. 4 of Ref. [1]. One will easily find that $T^*(H)$ results in that TAFF behavior is related to the resistivity value $\rho > 1.4 \mu\Omega$ cm with resistivity ratio $\rho / \rho_n > 1.5\%$, where $\rho_n = \rho(140 \text{ K}, H = 0) \approx 93 \mu\Omega$ cm. In this case, Kim *et al.* gave the TAFF temperature interval over which the resistivity approximately changes from 1.4 to $10 \mu\Omega$ cm, or $\rho(T, H) / \rho_n$ approximately above 1.5%. This interval is apparently mismatched with the interval suggested by Palstra *et al.* Below temperature T^* , Kim *et al.* defined the critical state region, but they did not further present physical meaning for the region. In comparing with other HTSCs, it is very dubious that non-ohmic resistivity can be found around the so-called T^* . As a result, we argue that definitions of the TAFF and the critical state regions in the article are questionable and the TAFF region ought to relate to the temperature interval as suggested by Palstra *et al.*; besides, we argue that the definition of T_{ff} is incorrect in the paper [2].

Normally, the TAFF resistivity is expressed as $\rho = \rho_0 \exp(-U_0/T)$ with the activation energy $U_0(T, H) = U_0(0, H)(1 - t)^\beta$, where $t = T/T_c$, β is constant, and T_c is the critical temperature. Considering the interlayer decoupling in high fields, Zhang *et al.* [2] suggested an empirical relation

$$\rho = \rho_{0f} \exp[-U(T, H)/T], \quad (1)$$

with

$$U(T, H) = g(H)f(t), \quad (2)$$

and

$$f = (1 - t)^\beta, \quad (3)$$

where ρ_{0f} is constant, and g and β are magnetic field dependent. Using the progression $(1 - t)^\beta = 1 - \beta t + \beta(\beta - 1)t^2/2! - \beta(\beta - 1)(\beta - 2)t^3/3! + \dots$, we have $\ln \rho \approx$

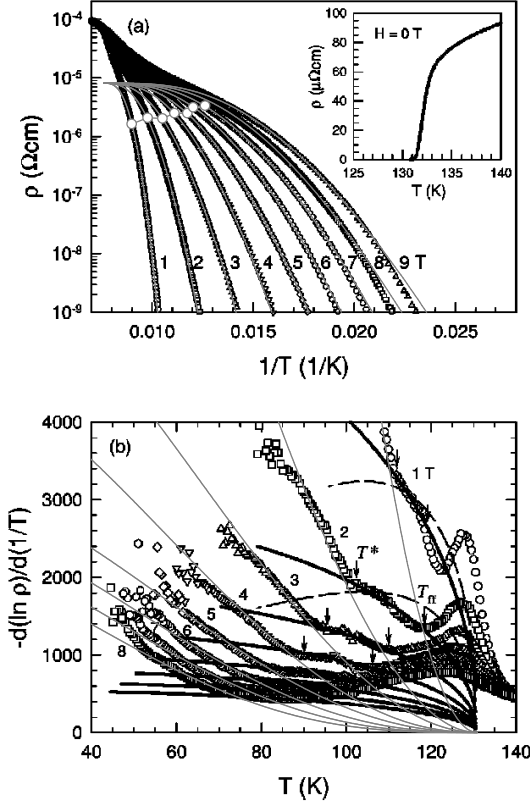


FIG. 1: (a) Arrhenius plot of $\rho(T, H)$ from Ref. [1]. The gray circles correspond to $\rho(1/T^*, H)$ data where $H(T^*)$ was determined from Fig.4 of Ref. [1]. (b) $-\partial \ln \rho(T, H)/\partial T_{ff}^{-1}$ curves from Ref. [1]. The black lines, the black dashed lines, arrows, T^* , and T_{ff} are presented by the authors [1]. The gray lines in (a) and (b) are our regressions using $\rho_{0f} = 8 \mu\Omega \text{ cm}$ for the curves (see text for more details).

$(\ln \rho_{0f} + g\beta/T_c) - (g/T)[1 + \beta(\beta - 1)t^2/2! - \beta(\beta - 1)(\beta - 2)t^3/3! + \dots]$, where the term $(\ln \rho_{0f} + g\beta/T_c) \approx \ln \rho_0$ is temperature independent. With $\beta = 1$, we have $\ln \rho_0 \approx \ln \rho_{0f} + g/T_c$. However, we find if β largely deviates from $\beta = 1$, the relation of $\ln \rho_0 \approx \ln \rho_{0f} + g\beta/T_c$ will bring in large uncertainty and errors for determining ρ_{0f} and T_c in the relation of $\ln \rho = \ln \rho_{0f} + g\beta/T_c$ plot (see Ref.[2]), as the value of the local slope $-\partial \ln \rho(T, H)/\partial T^{-1}$ largely changes from one local temperature to the other as shown in Fig. 1(b). This means that we shall determine the ρ_{0f} value in the other way when β largely deviates from $\beta = 1$.

Accordingly, we must determine four free parameters T_c , ρ_{0f} , $g(H)$, and $\beta(H)$ using Eqs.(1), (2), and (3) with the experimental data. Generally, T_c and ρ_{0f} are magnetic field independent and therefore can be eliminated from the free parameter list in each magnetic field. In simplicity, we follow the selection of Kim *et al.* to take $T_c = 131 \text{ K}$ (this will not lead to large errors as the transition width is less than 2 K in zero magnetic field and T_c shall be determined around the transition interval). We consider the resistivity value for ρ_{0f} (by trial and er-

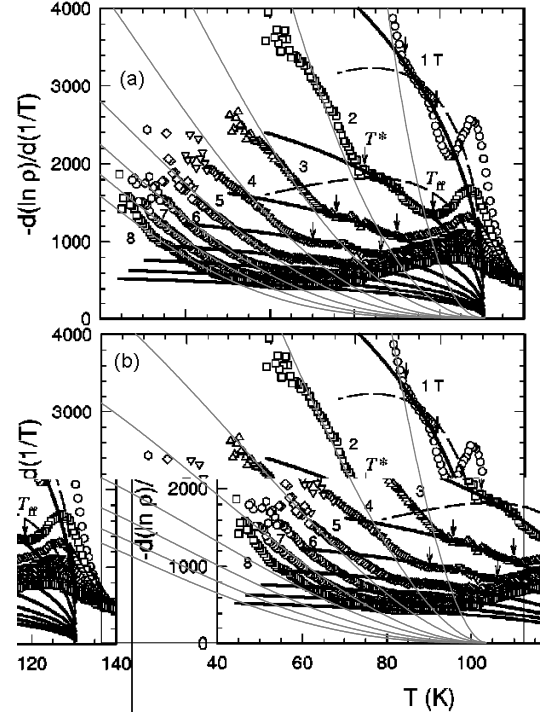


FIG. 2: The gray lines in (a) and (b) are our regressions using (a) $\rho_{0f} = 6 \mu\Omega \text{ cm}$, and (b) $\rho_{0f} = 10 \mu\Omega \text{ cm}$ for $-\partial \ln \rho(T, H)/\partial T_{ff}^{-1}$ curves.

ror) which is not only getting better regression for each $\rho(T, H)$ curve in TAFF region, but also is in good agreement with each $-\partial \ln \rho(T, H)/\partial T^{-1}$. Hence, this will leave only two free parameters g and β for each magnetic field. At first, we use the formula

$$U(T, H) \approx T \ln[\rho_{0f}/\rho(T, H)] \quad (4)$$

with $\rho(T, H)$ data to determine the parameters, and then check the parameters with corresponding regressions for the curves in Figs. 1(a) and (b). The gray solid lines in Figs. 1(a) and (b) show the results which we take $\rho_{0f} = 8 \mu\Omega \text{ cm}$ for regressions. One will find that the regressions are in good agreement with the data in the temperature interval where the resistivity roughly changing from 10^{-2} to $1 \mu\Omega \text{ cm}$. Note that the interval matches the temperature interval suggested by Palstra *et al.* [3].

In fact, a ρ_{0f} value can be selected in a broad range without changing the consistent matches of all the fits for $U(T, H)$ and $\rho(T, H)$ curves in TAFF region. However, changing ρ_{0f} value will lead to changes of fitting parameters and still results in uncertainty in analysis. This means that we can not decide the ρ_{0f} value which is only good for the fits of U or ρ curves, and we have to check the results with $-\partial \ln \rho(T, H)/\partial T^{-1}$ relation. We find that the value of ρ_{0f} will change the consistent matches of the fits for $-\partial \ln \rho(T, H)/\partial T^{-1}$ curves in TAFF region.

Figures 2(a) and (b) show the fitting results of $-\partial \ln \rho(T, H)/\partial T^{-1}$ with $\rho_{0f} = 6 \mu\Omega \text{ cm}$ and $10 \mu\Omega \text{ cm}$, respectively. The fits are not good in Fig. 2(a) for low

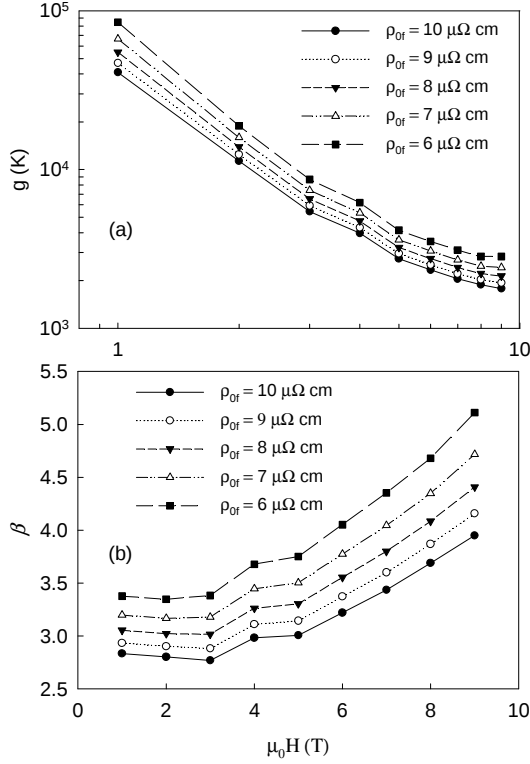


FIG. 3: (a) $g(H)$ and (b) $\beta(H)$ determined with different ρ_{0f} values.

fields and in Fig. 2(b) for high fields, respectively, while they are in good agreement with experimental data in other field ranges. The analysis suggests that we have $\rho_{0f} = 8.0 \pm 1.5 \mu\Omega \text{ cm}$ for getting better fits for all $-\partial \ln \rho(T, H) / \partial T^{-1}$ curves. The deviations between the regressions and experimental data in low temperature range are possibly due to competing relations between coupling and decoupling and between pinning and depinning.

Figures 3(a) and (b) represent $g(H)$ and $\beta(H)$ data for $\rho_{0f} = 6, 7, 8, 9, 10 \mu\Omega \text{ cm}$, respectively. With $\rho_{0f} = 8 \mu\Omega \text{ cm}$, we find that $g \sim H^{-1.94}$ and $\beta \approx 3$ for $1 \leq \mu_0 H \leq 3$ T, while $g \sim H^{-0.73}$ and β approximately linearly increases with H for $5 \leq \mu_0 H \leq 9$ T. The characteristic changes of g and β around $\mu_0 H = 4$ T are probably due to the crossover from 3D to 2D as discussed in Ref. [2].

In summary, we suggest that the analysis of activation energies and definitions of the four different vortex regions are incorrect in Ref. [1], as the TAFF temperature interval presented in it does not match the interval suggested by Palstra *et al.* [3]. Using the temperature interval suggested by Palstra *et al.*, we find that the empirical activation energy form suggested by Zhang *et al.* [2] is in good agreement with the lower resistivity data.

This work has been financially supported by the National Science Foundation of China (Grant No. 10174091).

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